

### GBJ35005 - GBJ3510/G

**Mechanical Data** 

Single Phase 35Amp Glass passivated Bridge Rectifiers

### **Features**

- · Glass passivated die construction
- · Low forward voltage drop
- · High current capability
- · High surge current capability
- Plastic material-UL flammability 94V-0
- The G suffix is uses for photoresist chip, otherwise it is a knife scraping chip

### **MECHANICAL DATA**

· Case: Molded plastic, GBJ

• Terminals: Plated Leads Solderable perMIL-STD-202, Method 208

· Polarity: As Marked on Case

Mounting Position: Any Marking: Type Number

· Lead Free: For RoHS / Lead Free Version

# 1.Output Anode(+) GBJ 2.Input pin(~) 3.Input pin(~) 4.Output Cathode(-)

### Maximum Ratings And Electrical Characteristics (@T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	GBJ	Unit
		35005	3501	3502	3504	3506	3508	3510	
$V_{RRM}$	repetitive peak reverse voltage	50	100	200	400	600	800	1000	
$V_{RWM}$	Working Peak Reverse Voltage			1000	V				
$V_{RMS}$	RMS voltage			700					
$V_{DC}$	DC blocking voltage	50	100	200	400	600	800	1000	
IF <sub>AV</sub>	Average Rectified Output	35.0						А	
	Current (Note 1)@T <sub>C</sub> =90°C								
I <sub>FSM</sub>	Peak forward surge current, 8.3ms single	370						Α	
	half sine-wave								
$I_t^2$	I <sub>t</sub> <sup>2</sup> Rating for fusing (t<8.3ms)	568.135				A <sub>S</sub> <sup>2</sup>			
$V_{FM}$	Forward Voltage element @IF=17.5A	1.05				V			
I <sub>R</sub>	Peak Reverse Current@T <sub>A</sub> =25°C	5.0					uA		
	at rated DC blocking voltage@ T <sub>A</sub> =125°C	500							
CJ	Typical junction capacitance	75			pF				
$R_{\theta JA}$	Between junction and ambient, Without heatsink	22					°C/W		
$R_{\theta JC}$	Between junction and case, With heatsink	8.0							
TJ	Operation Temperature Range	-55 to +150					°C		
T <sub>STG</sub>	Storage Temperature Range	-55 to +150							

Note:(1)Thermal resistance from junction to case per element. Unit mounted on 75x75x1.6mm aluminum plate heat sink. BORN SEMICONDUCTOR, INC. ALL

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### **Ratings And Characteristic Curves**

Figure 1: Output Current Derating Curve

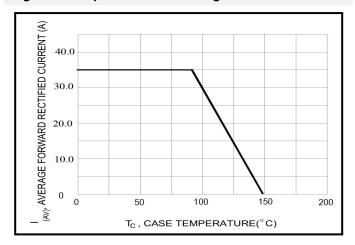


Figure 2: Typical Forward Characteristics (per leg)

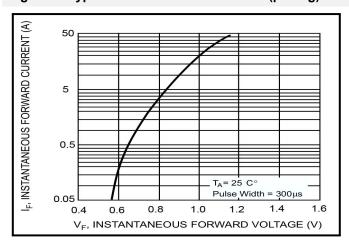
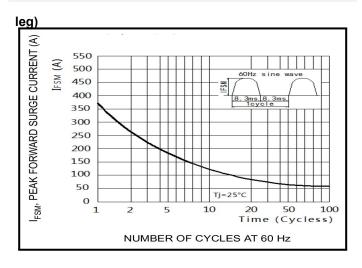


Figure 3:Maximum Peak Forward Surge Current (per



**Figure 4:Typical Junction Capacitance** 

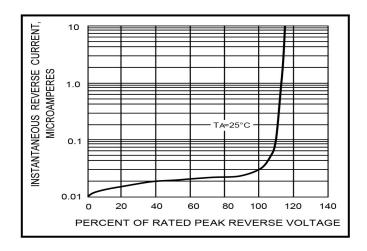
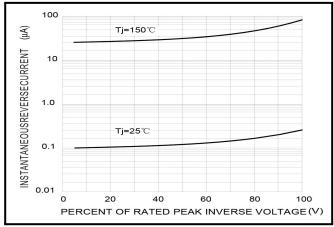


Figure 5:TYPICAL REVERSE CHARACTERISTICS



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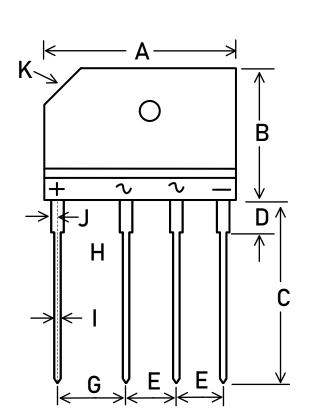


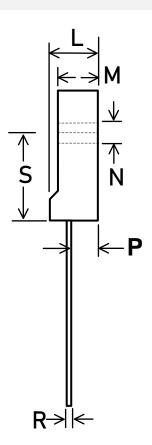


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## **Outline Drawing -GBJ**





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	MILLIMETER					
SYMBOL	MIN.	MAX.				
Α	29.70	30.3				
В	19.70	20.3				
С	17.00	18.00				
D	3.80	4.20				
E	7.30	7.70				
G	9.80	10.20				
Н	2.00	2.40				
I	0.90	1.10				
J	2.30	2.70				
K	3.0x45°					
L	4.40	4.80				
М	3.40	3.80				
N	3.10	3.40				
Р	2.50	2.90				
R	0.60	0.80				
S	10.80	11.20				